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June 2014



74LVX08 Low Voltage Quad 2-Input AND Gate

Features

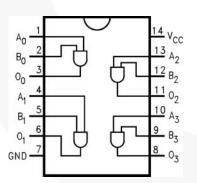
- Input Voltage Level Translation from 5 V to 3 V
- Ideal for Low-power / Low-Noise 3.3 V Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic threshold Performance

Ordering Information

Part Number | Top Mark Package Packing Method **Packing Description** 14-Lead Small Outline Integrated Circuit, JEDEC 74LVX08M LVX08 SOIC 14L Rail MS-012, 0.150 inch Narrow 14-Lead Small Outline Integrated Circuit, JEDEC 74LVX08MX LVX08 SOIC 14L Tape and Reel MS-012, 0.150 inch Narrow 14-Lead Thin Shrink Small Outline Package, 74LVX08MTCX LVX08 TSSOP 14L Tape and Reel JEDEC MO-153, 4.4 mm Wide

All packages are lead free per JEDEC: J-STD-020B standard.

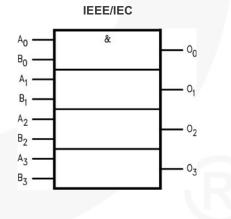
Connection Diagram



Pin Description

Pin Names	Description
A _n , B _n	Inputs
O _n	Outputs

Logic Symbol



Description

The LVX08 contains four 2-input AND gates. The inputs tolerate voltages up to 7 V allowing the interface of 5 V systems to 3 V systems.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Rating		
V _{CC}	Supply Voltage		-0.5 V to 7.0 V		
I _{IK}	DC Input Diode Current, V _I = -0.5 V		-20 mA		
VI	DC Input Voltage		-0.5 V to 7.0 V		
	DC Output Diada Current	V _O = -0.5 V	-20 mA		
ЮК	DC Output Diode Current	$V_{O} = V_{CC} + 0.5 V$	+20 mA		
Vo	DC Output Voltage		-0.5 V to V _{CC} + 0.5 V		
Ι _Ο	DC Output Source or Sink Current		±25 mA		
I _{CC} or I _{GND}	DC V _{CC} or Ground Current		±50 mA		
T _{STG}	Storage Temperature		-65°C to 150°C		
Р	Power Dissipation		180 mW		
TL	Lead Temperature (Soldering, 10 seconds)		240°C		

Recommended Operating Conditions⁽¹⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	2.0 V to 3.6 V
VI	Input Voltage	0 V to 5.5 V
V _O	Output Voltage	0 V to V _{CC}
Τ _Α	Operating Temperature	-40°C to 85°C
Δt / ΔV	Input Rise and Fall Time	0 ns/V to 100 ns/V

Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

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Symbol	Parameter	v _{cc}	Conditions	T _A = 25°C			T _A = -40°C to +85°C		Unit
				Min.	Тур.	Max.	Min.	Max.	
		2.0		1.5			1.5		
V_{IH}	HIGH Level Input Voltage	3.0		2.0			2.0		V
	vollago	3.6		2.4			2.4		
		2.0				0.5		0.5	
V _{IL}	LOW Level Input Voltage	3.0				0.8		0.8	V
		3.6				0.8		0.8	
		2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \ \mu\text{A}$	1.9	2.0		1.9		
V _{OH}	HIGH Level Output Voltage 3.0	2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \ \mu\text{A}$	2.9	3.0		2.9		V
		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -4 \text{ mA}$	2.58			2.48		
	LOW Level Output Voltage 3.0	2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = -50 \ \mu\text{A}$		0.0	0.1		0.1	
V _{OL}		$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = -50 \ \mu\text{A}$		0.0	0.1		0.1	V	
		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = -4 \text{ mA}$			0.36		0.44	
I _{IN}	Input Leakage Current	3.6	$V_{IN} = 5.5 V \text{ or GND}$			±0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	3.6	$V_{IN} = V_{CC}$ or GND			2.0		20.0	μA

Noise Characteristics⁽²⁾

Symbol	Parameter	$\mathbf{V} = (\mathbf{V})$	C _L (pF)	T _A = 25°C		Unit
Symbol	Faiametei	$V_{CC}(V)$		Тур.	Limit	Unit
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	50	0.3	0.5	V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	50	-0.3	-0.5	V
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3	50		2.0	V
V _{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3	50	/	0.8	V

Note:

2. Input $t_r = t_f = 3 \text{ ns}$

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AC Electrical Characteristics

Symbol	Parameter	$V_{CC}(V)$	C _L (pF)	T _A = 25°C			T _A = -40°C to +85°C		Unit
				Min.	Тур.	Max.	Min.	Max.	
t _{PLH} , t _{PHL}	Propagation Delay Time	2.7	15		6.3	11.4	1.0	13.5	ns
			50		8.8	14.9	1.0	17.0	
		3.3 ± 0.3	15		4.8	7.1	1.0	8.5	
			3.3 ± 0.3	50		7.3	10.6	1.0	12.0
t _{OSLH} , t _{OSHL}	Output to Output Skew ⁽³⁾	2.7	50			1.5		1.5	20
		3.3	50			1.5		1.5	ns

Note:

3. Parameter guaranteed by design $t_{OSLH} = I t_{PLHm} - t_{PLHn} I$, $t_{OSHL} = I t_{PHLm} - t_{PHLn} I$.

Capacitance

Symbol Pa	Parameter		_A = 25°	C	T _A = -40°C to +85°C		Unit
		Min.	Тур.	Max.	Min.	Max.	
C _{IN}	Input Capacitance		4	10		10	pF
C _{PD}	Power Dissipation Capacitance ⁽⁴⁾		18				pF

Note:

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} \times I_{CC}}{4 \text{ (per Gate)}}$





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